#### **Data Sheet**



# ASCKCx00-xxxxx0x0x0x02 1608 DFN-2 Surface-Mount LED



#### Overview

The Broadcom<sup>®</sup> ASCKCx00 surface-mount LEDs utilize AllnGaP and InGaN chips in a small form factor DFN-2 package. The LEDs are designed with high-reliability performance to work under a wide range of environmental conditions. The small form factor package enables flexibilities in product designs. The LEDs are ideal for a wide range of applications.

To facilitate easy pick-and-place assembly, the LEDs are packed in tape and reel. Every reel is shipped in single intensity and color bin, to provide close uniformity.

#### **Features**

- High-reliability package with enhanced silicone resin encapsulation
- Available in yellow-green, amber, red, blue, green, and Phosphor Converted (PC) amber.
- Wide 120° viewing angle
- Small package form factor and thickness for better design flexibility
- JEDEC MSL 3

# **Applications**

- Status indicators
- Indoor information signs and displays
- Backlight for switches
- Wearables and portable devices
- Office automations, home appliances, industrial equipment:
  - Front-panel backlighting
  - Push-button backlighting
  - Display backlighting
  - Keypad backlighting
  - Symbol backlighting

**CAUTION!** This LED is ESD sensitive. Observe appropriate precautions during handling and processing. Refer to application note AN-1142 for additional details.

Figure 1: Package Drawing for Yellow-Green and Green

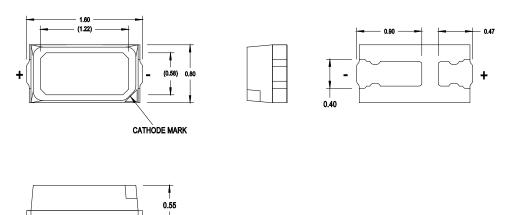
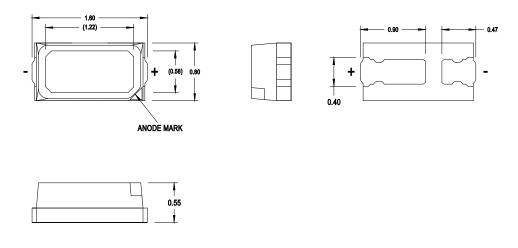




Figure 2: Package Drawing for Red, Amber, Blue, and PC Amber





#### NOTE:

- 1. All dimensions are in millimeters (mm).
- 2. Tolerance is ±0.20 mm unless otherwise specified.
- 3. Encapsulation = silicone.
- 4. Terminal finish = silver plating.
- 5. Dimensions in brackets are for reference only.

# Device Selection Guide ( $T_J = 25$ °C, $I_F = 20$ mA)

			Luminou	s Intensity, I <sub>V</sub>	(mcd) <sup>a, b</sup>	Luminous Flux, Φ <sub>V</sub> (lm) <sup>c</sup>
Part Number	Color	Die Type	Min.	Тур.	Max.	Тур.
ASCKCA00-BU4V4020502	Amber	AllnGaP	525	650	967	2.0
ASCKCR00-BU5V5020402	Red	AllnGaP	613	730	1125	2.2
ASCKCF00-AP5R5010402	Yellow-Green	AllnGaP	61.3	80	180	0.3
ASCKCB00-NS3T4010302	Blue	InGaN	180	250	386	0.8
ASCKCG00-NW5X5020302	Green	InGaN	1540	1800	2850	5.4
ASCKC500-NW5X4040402	PC Amber	InGaN	1540	1900	2450	5.4

a. The luminous intensity,  $I_V$ , is measured at the mechanical axis of the package and it is tested with a single-current pulse condition. The actual peak of the spatial radiation pattern may not be aligned with the axis.

# **Absolute Maximum Ratings**

Parameters	AlinGaP	InGaN	Unit	
DC Forward Current <sup>a</sup>	30	20	mA	
Peak Forward Current <sup>b</sup>	100	100	mA	
Power Dissipation	72	72	mW	
Reverse Voltage	Not de	Not designed for reverse bias operation		
LED Junction Temperature	110	95	°C	
Operating Temperature Range	-40 to +85	-40 to +85	°C	
Storage Temperature Range	-40 to +85	-40 to +85	°C	

a. Derate linearly as shown in Figure 19, Figure 20, Figure 21, and Figure 22.

b. Luminous intensity tolerance is ±12%.

c. For reference only.

b. Duty factor is 10%, frequency is1 kHz,  $T_A$  is 25°C.

# Optical and Electrical Characteristics ( $T_J = 25$ °C, $I_F = 20$ mA)

Parameters	Min.	Тур.	Max.	Unit
Viewing Angle, 2θ <sub>½</sub> <sup>a</sup>	_	120	_	٥
Forward Voltage, V <sub>F</sub> <sup>b</sup>				V
Amber, Red, Yellow-Green	1.8	2.1	2.4	
Blue	2.6	3.1	3.6	
Green	2.6	3.3	3.6	
PC Amber	2.6	3.0	3.6	
Reverse Current, I <sub>R</sub> at V <sub>R</sub> = 5V <sup>c</sup>	_	_	10	μA
Dominant Wavelength, λ <sub>d</sub> <sup>d</sup>				nm
Amber	583.0	589	595.0	
Red	615.0	622	630.0	
Yellow-Green	564.5	572	576.5	
Blue	460.0	467	475.0	
Green	520.0	524	530.0	
PC Amber	_	590	_	
Peak Wavelength, λ <sub>p</sub>				nm
Amber	_	592	_	
Red	_	632	_	
Yellow-Green	_	573	_	
Blue	_	462	_	
Green	_	517	_	
PC Amber	_	602	_	
Thermal Resistance, R <sub>θJ-S</sub> <sup>e</sup>				°C/W
Amber	_	90	_	
Red	_	90	_	
Yellow-Green	_	190	_	
Blue	_	180	_	
Green	_	180	_	
PC Amber	_	80	_	

a.  $\,\theta_{1\!/\!_2}$  is the off-axis angle where the luminous intensity is half of the peak intensity.

b. Forward voltage tolerance is ±0.1V.

c. Indicates product final test condition. Long-term reverse bias is not recommended.

d. The dominant wavelength is derived from the CIE Chromaticity diagram and represents the perceived color of the device.

e. Thermal resistance from LED junction to solder point.

# **Part Numbering System**

A S C K C  $x_1$  0 0 -  $x_2$   $x_3$   $x_4$   $x_5$   $x_6$  0  $x_7$  0  $x_8$  0 2

Code	Description	Option		
x <sub>1</sub>	Color	А	Amber	
		R	Red	
		F	Yellow-Green	
		В	Blue	
		G	Green	
x <sub>2</sub>	Die Type	A, B	AllnGaP	
		N	InGaN	
x <sub>3</sub> x <sub>4</sub>	Minimum Intensity Bin	Refer to Inte	nsity Bin Limits (CAT).	
x <sub>5</sub> x <sub>6</sub>	Maximum Intensity Bin			
x <sub>7</sub>	Minimum Color Bin	Refer to Col	or Bin Limits (BIN).	
x <sub>8</sub>	Maximum Color Bin			

### **Part Number Example**

#### ASCKCB00-NS3T4010302

x<sub>1</sub> : B - Blue

 $x_2$  : N – InGaN

 $x_3 x_4$  : S3 — Maximum intensity bin S3  $x_5 x_6$  : T4 — Maximum intensity bin T4

 $egin{array}{llll} x_7 & : 1 & & - & \mbox{Minimum color bin 1} \\ x_8 & : 3 & & - & \mbox{Maximum color bin 3} \\ \end{array}$ 

# **Bin Information**

# **Intensity Bin Limits (CAT)**

	Luminous Intensity, I <sub>V</sub> (mcd)		
Bin ID	Min.	Max.	
P5	61.3	71.5	
Q3	71.5	83.2	
Q4	83.2	96.7	
Q5	96.7	112.5	
R3	112.5	132	
R4	132	154	
R5	154	180	
S3	180	210	
S4	210	245	
S5	245	285	
Т3	285	332	
T4	332	386	
T5	386	450	
U3	450	525	
U4	525	613	
U5	613	715	
V3	715	832	
V4	832	967	
V5	967	1125	
W3	1125	1320	
W4	1320	1540	
W5	1540	1800	
Х3	1800	2100	
X4	2100	2450	
X5	2450	2850	

# Forward Voltage Bin Limits (V<sub>F</sub>)

	Forward Voltage, V <sub>F</sub> (V)		
Bin ID	Min.	Max.	
F00	1.8	2.0	
F01	2.0	2.2	
F02	2.2	2.4	
F03	2.4	2.6	
F04	2.6	2.8	
F05	2.8	3.0	
F06	3.0	3.2	
F07	3.2	3.4	
F08	3.4	3.6	

Tolerance =  $\pm 0.1V$ 

Tolerance = ±12%

# **Color Bin Limits (BIN)**

# **Amber**

	Dominant Wavelength, $\lambda_{d}$ (nm)	
Bin ID	Min.	Max.
2	583.0	586.0
3	586.0	589.0
4	589.0	592.0
5	592.0	595.0

### Green

	Dominant Wavelength, $\lambda_{\mathrm{d}}$ (nm)	
Bin ID	Min.	Max.
2	520.0	525.0
3	525.0	530.0

Tolerance = ±1 nm

# Red

	Dominant Wavelength, $\lambda_{d}$ (nm)		
Bin ID	Min.	Max.	
2	615.0	620.0	
3	620.0	625.0	
4	625.0	630.0	

### Yellow-Green

	Dominant Wavelength, $\lambda_{d}$ (nm)	
Bin ID	Min.	Max.
1	564.5	567.5
2	567.5	570.5
3	570.5	573.5
4	573.5	576.5

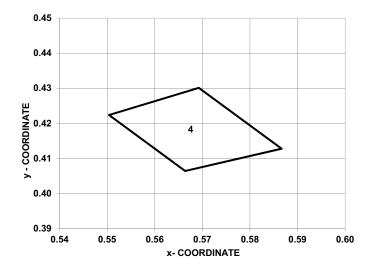
### Blue

	Dominant Wavelength, $\lambda_{d}$ (nm)		
Bin ID	Min.	Max.	
1	460.0	465.0	
2	465.0	470.0	
3	470.0	475.0	

#### **PC Amber**

	<b>Chromaticity Coordinates</b>		
Bin ID	x	у	
4	0.5504	0.4224	
	0.5693	0.4301	
	0.5867	0.4128	
	0.5664	0.4064	

Figure 3: Chromaticity Diagram



**NOTE:** The corresponding dominant wavelength is from 589 nm to 592 nm.

Example of bin information on reel and packaging label:

CAT: S4 - Intensity bin S4

BIN: 3 — Color bin 3 VF: F01 — VF bin F01

Figure 4: Spectral Power Distribution

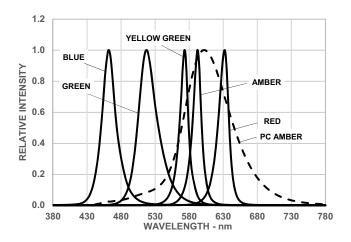


Figure 6: Relative Luminous Intensity vs. Mono Pulse Current (AllnGaP)

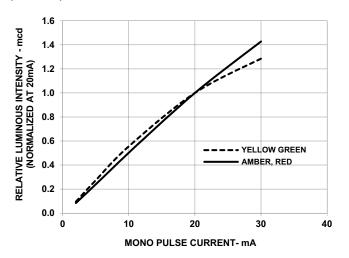


Figure 8: Radiation Pattern

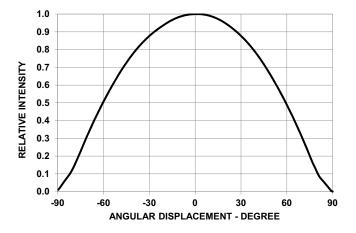


Figure 5: Forward Current vs. Forward Voltage

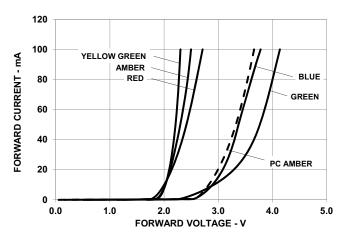


Figure 7: Relative Luminous Intensity vs. Mono Pulse Current (InGaN)

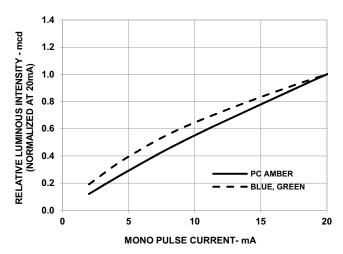


Figure 9: Dominant Wavelength Shift vs. Mono Pulse Current (AllnGaP)

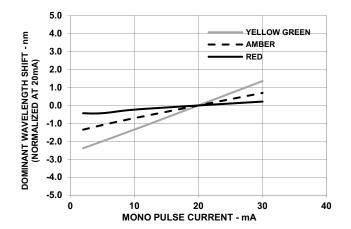


Figure 10: Dominant Wavelength Shift vs. Mono Pulse Current (InGaN)

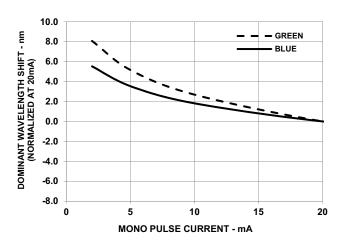


Figure 12: Forward Voltage Shift vs. Junction Temperature (AllnGaP)

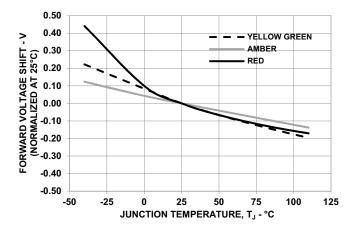


Figure 14: Relative Luminous Intensity vs. Junction Temperature (AllnGaP)

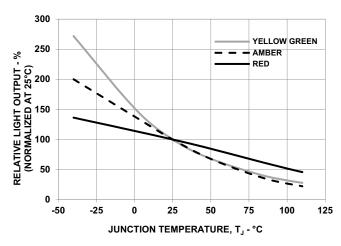


Figure 11: Chromaticity Coordinate Shift vs. Mono Pulse Current (PC Amber)

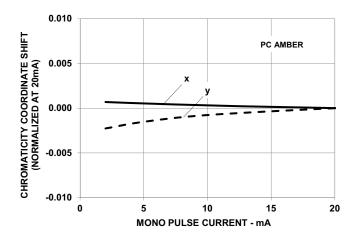


Figure 13: Forward Voltage Shift vs. Junction Temperature (InGaN)

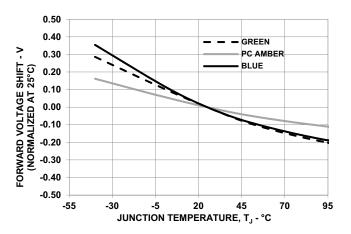


Figure 15: Relative Luminous Intensity vs. Junction Temperature (InGaN)

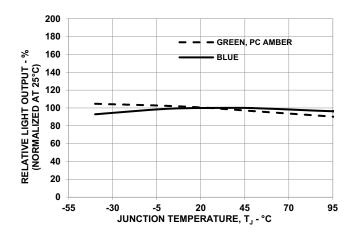


Figure 16: Dominant Wavelength Shift vs. Junction Temperature (AllnGaP)

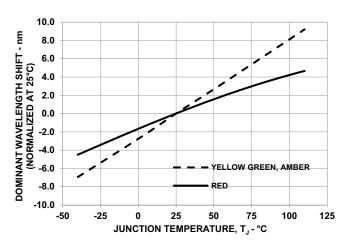


Figure 18: Chromaticity Coordinate Shift vs. Junction Temperature (PC Amber)

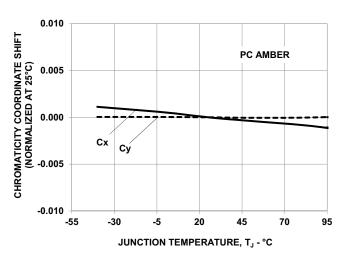


Figure 20: Maximum Forward Current vs. Solder Point Temperature. Derated Based on T<sub>JMAX</sub> = 110°C (AlInGaP)

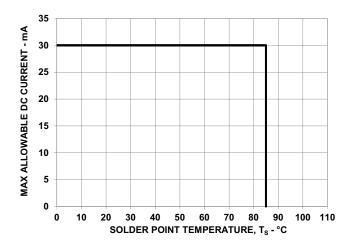


Figure 17: Dominant Wavelength Shift vs. Junction Temperature (InGaN)

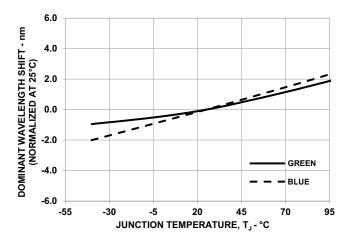


Figure 19: Maximum Forward Current vs. Ambient Temperature. Derated Based on T<sub>JMAX</sub> = 110°C (AllnGaP)

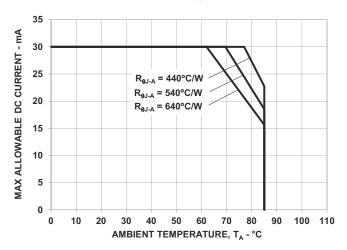


Figure 21: Maximum Forward Current vs. Ambient Temperature. Derated Based on T<sub>JMAX</sub> = 95°C (InGaN)

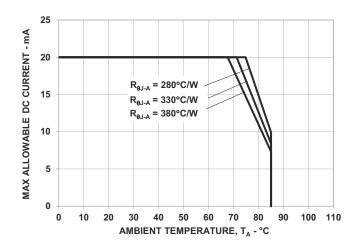


Figure 22: Maximum Forward Current vs. Solder Point Temperature. Derated Based on  $T_{JMAX} = 95^{\circ}C$  (InGaN)

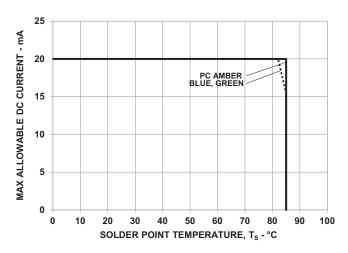
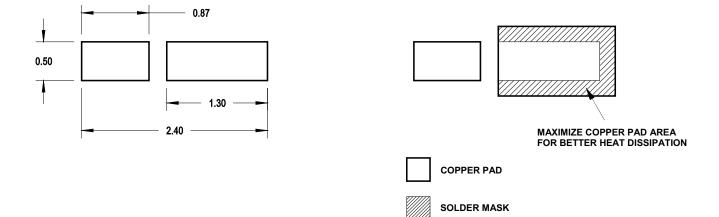
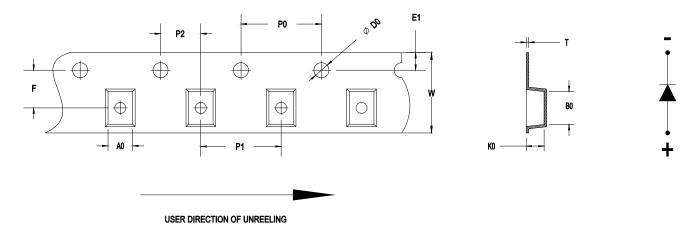


Figure 23: Recommended Soldering Land Pattern



NOTE: All dimensions are in millimeters (mm).

Figure 24: Carrier Tape Dimensions

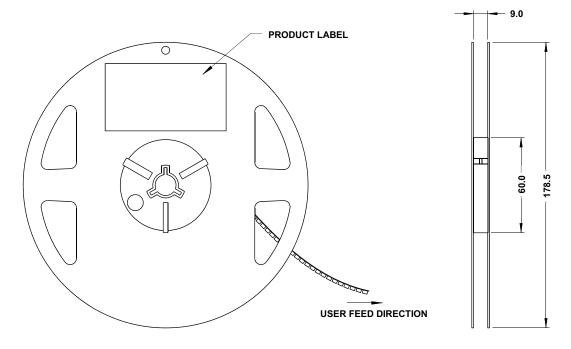


F	P0	P1	P2	D0	E1	w
3.50 ± 0.05	4.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.05	1.55 + 0.05	1.75 ± 0.10	8.00 ± 0.30
Т	В0	K0	A0			
0.20 ± 0.05	1.75 ± 0.10	0.68 ± 0.10	0.90 ± 0.10			

#### NOTE:

- 1. All dimensions are in millimeters (mm).
- 2. Quantity per reel: 4000 pieces.

Figure 25: Reel Dimensions



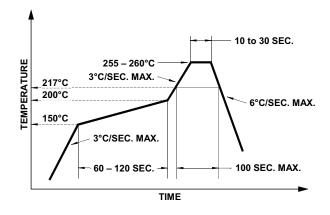
NOTE: All dimensions are in millimeters (mm).

## **Precautionary Notes**

#### Soldering

- Do not perform reflow soldering more than twice.
   Observe necessary precautions of handling moisture-sensitive devices as stated in the following section.
- Do not apply any pressure or force on the LED during reflow and after reflow when the LED is still hot.
- Use reflow soldering to solder the LED. Use hand soldering only for rework if unavoidable, but it must be strictly controlled to following conditions:
  - Soldering iron tip temperature = 315°C maximum
  - Soldering duration = 3 seconds maximum
  - Number of cycles = 1 only
  - Power of soldering iron = 50W maximum
- Do not touch the LED package body with the soldering iron except for the soldering terminals, as it may cause damage to the LED.
- Confirm beforehand whether the functionality and performance of the LED is affected by soldering with hand soldering.

Figure 26: Recommended Lead-Free Reflow Soldering Profile



#### **Handling Precautions**

The encapsulation material of the LED is made of silicone for better product reliability. Compared to epoxy encapsulant, which is hard and brittle, silicone is softer and flexible. Observe special handling precautions during assembly of silicone encapsulated LED products. Failure to comply might lead to damage and premature failure of the LED. Refer to Broadcom Application Note AN5288, Silicone Encapsulation for LED: Advantages and Handling Precautions. for additional information.

- Do not poke sharp objects into the silicone encapsulant.
   Sharp objects, such as tweezers or syringes, might apply excessive force or even pierce through the silicone and induce failures to the LED die or wire bond.
- Do not touch the silicone encapsulant. Uncontrolled force acting on the silicone encapsulant might result in excessive stress on the wire bond. Hold the LED by the body only.
- Do not stack assembled PCBs together. Use an appropriate rack to hold the PCBs.
- The surface of silicone material attracts dust and dirt easier than epoxy, due to its surface tackiness. To remove foreign particles on the surface of silicone, use a cotton bud with isopropyl alcohol (IPA). During cleaning, rub the surface gently without putting too much pressure on the silicone. Ultrasonic cleaning is not recommended.

#### **Handling of Moisture-Sensitive Devices**

This product has a Moisture Sensitive Level 3 rating per JEDEC J-STD-020. Refer to Broadcom Application Note AN5305, *Handling of Moisture Sensitive Surface Mount Devices*, for additional details and a review of proper handling procedures.

#### Before use:

- An unopened moisture barrier bag (MBB) can be stored at <40°C/90% RH for 12 months. If the actual shelf life has exceeded 12 months and the Humidity Indicator Card (HIC) indicates that baking is not required, then it is safe to reflow the LEDs per the original MSL rating.
- Do not open the MBB prior to assembly (for example, for IQC). If unavoidable, MBB must be properly resealed with fresh desiccant and HIC. The exposed duration must be taken in as floor life.
- Control after opening the MBB:
  - Read the HIC immediately upon opening of MBB.
  - Keep the LEDs at <30°/60% RH at all times, and complete all high temperature-related processes, including soldering, curing, or rework within 168 hours.
- Control for unfinished reel:

Store unused LEDs in a sealed MBB with desiccant or a desiccator at <5% RH.

Control of assembled boards:

If the PCB soldered with the LEDs is to be subjected to other high-temperature processes, store the PCB in a sealed MBB with desiccant or desiccator at <5% RH to ensure that all LEDs have not exceeded their floor life of 168 hours.

- Baking is required if:
  - The HIC indicator indicates a change in color for 10% and 5%, as stated on the HIC.
  - The LEDs are exposed to conditions of >30°C/60% RH at any time.
  - The LED's floor life exceeded 168 hours.

The recommended baking condition is  $60^{\circ}\text{C} \pm 5^{\circ}\text{C}$  for 20 hours.

Baking can only be done once.

Storage:

The soldering terminals of these Broadcom LEDs are silver plated. If the LEDs are exposed in an ambient environment for too long, the silver plating might be oxidized, thus affecting its solderability performance. As such, keep unused LEDs in a sealed MBB with desiccant or in a desiccator at <5% RH.

#### **Application Precautions**

- The drive current of the LED must not exceed the maximum allowable limit across temperature as stated in the data sheet. Constant current driving is recommended to ensure consistent performance.
- Circuit design must cater to the whole range of forward voltage (V<sub>F</sub>) of the LEDs to ensure the intended drive current can always be achieved.
- The LED exhibits slightly different characteristics at different drive currents, which may result in a larger variation of performance (meaning: intensity, wavelength, and forward voltage). Set the application current as close as possible to the test current to minimize these variations.
- The LED is not intended for reverse bias. Use other appropriate components for such purposes.
- Do not use the LED in the vicinity of material with sulfur content or in environments of high gaseous sulfur compounds and corrosive elements. Examples of material that might contain sulfur are rubber gaskets, room-temperature vulcanizing (RTV) silicone rubber, rubber gloves, and so on. Prolonged exposure to such environments may affect the optical characteristics and product life of the LED.
- White LEDs must not be exposed to acidic environments and must not be used in the vicinity of any compound that may have acidic outgas, such as, but not limited to, acrylate adhesive. These environments have an adverse effect on LED performance.
- Avoid rapid change in ambient temperature, especially in high-humidity environments, because they cause condensation on the LED.
- If the LED is intended to be used in a harsh or outdoor environment, protect the LED against damages caused by rain water, water, dust, oil, corrosive gases, external mechanical stresses, and so on.

#### **Thermal Management**

The optical, electrical, and reliability characteristics of the LED are affected by temperature. Keep the junction temperature  $(T_J)$  of the LED below the allowable limit at all times.  $T_J$  can be calculated as follows:

$$T_J = T_A + R_{\theta J-A} \times I_F \times V_{Fmax}$$

where:

 $T_A$  = Ambient temperature (°C)

 $R_{\theta J-A}$  = Thermal resistance from LED junction to ambient (°C/W)

 $I_F$  = Forward current (A)

V<sub>Fmax</sub> = Maximum forward voltage (V)

The complication of using this formula lies in  $T_A$  and  $R_{\theta J-A}$ . Actual  $T_A$  is sometimes subjective and hard to determine.  $R_{\theta J-A}$  varies from system to system depending on design and is usually not known.

Another way of calculating  $T_J$  is by using the solder point temperature,  $T_S$  as follows:

$$T_J = T_S + R_{\theta J-S} \times I_F \times V_{Fmax}$$

where:

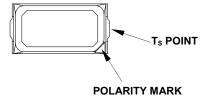
 $T_S$  = LED solder point temperature as shown in the following figure (°C)

 $R_{\theta J-S}$  = Thermal resistance from junction to solder point (°C/W)

 $I_F$  = Forward current (A)

V<sub>Fmax</sub> = Maximum forward voltage (V)

Figure 27: Solder Point Temperature on PCB



 $T_S$  can be easily measured by mounting a thermocouple on the soldering joint as shown in preceding figure, while  $R_{\theta J\text{-}S}$  is provided in the data sheet. Verify the  $T_S$  of the LED in the final product to ensure that the LEDs are operating within all maximum ratings stated in the data sheet.

#### **Eye Safety Precautions**

LEDs may pose optical hazards when in operation. Do not look directly at operating LEDs because it might be harmful to the eyes. For safety reasons, use appropriate shielding or personal protective equipment.

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